

# A System for measuring Temperature dependent Surface Photovoltage

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# Outline

Introduction

Theory

The Systems

Experimental: CPD

Experimental: SPV

Discussion & Conclusion



# Motivation

## The goal of this project is to...

- Use a new experimental Kelvin Probe (KP) system
- Add illumination to 'new' KP
- Compare results from 'new' KP to established, 'old' KPs
  - Does 'old' & 'new' Contact Potential Difference (CPD) agree?
  - Does 'old' & 'new' Surface Photovoltage (SPV) agree?
- Ultimately measure temperature dependent Surface Photovoltage (SPV(T)) with the new system

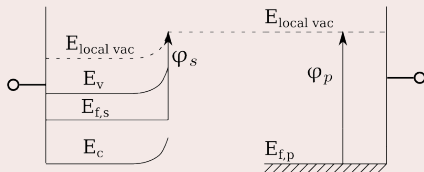
# The Contact Potential Difference (CPD)

## Physical Causes of CPD

The CPD is the difference in local vacuum levels, here defined as:

$CPD \equiv \varphi_{\text{Probe}} - \varphi_{\text{Sample}}$ ,  
 where  $\varphi$  is Work function

Semiconductor-Metal:



[1]

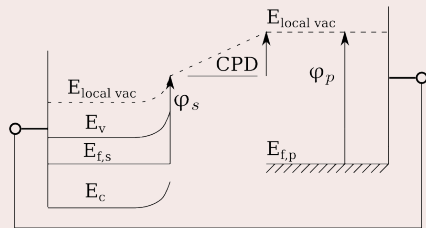
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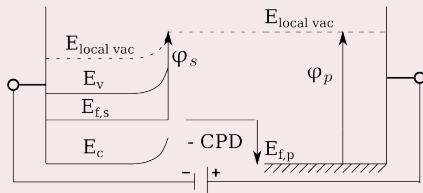
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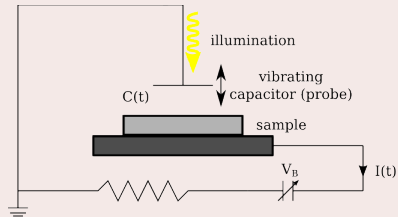
[1]

# The Contact Potential Difference (CPD)

## Measuring CPD: The Kelvin Probe (KP)

$$I(t) = \frac{dQ}{dt} = (CPD + V_b) \frac{dC}{dt}$$

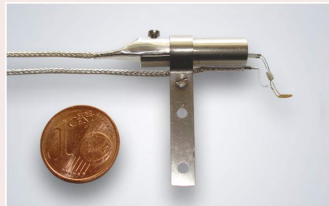
$$I(t) = 0 \quad \text{iff} \quad V_b = -CPD$$



## Established, 'old' KP Systems

### Ambient & Glovebox KPs

- Besocke KP head & controller
- Humidity controlled ambient
- Glovebox ( $< 5\text{ppm O}_2$  &  $\text{H}_2\text{O}$ )
- Xenon lamp & VariAC ( $\sim 80\text{ W}$ )
- Illumination is source of heat!

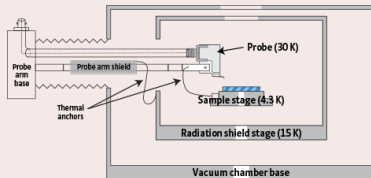


[2]

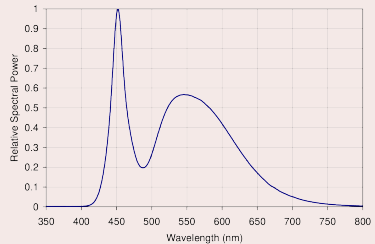


## 'New' System: Cryostat with a KP

### Lakeshore Cryostat with Mc Allister KP & LED illumination



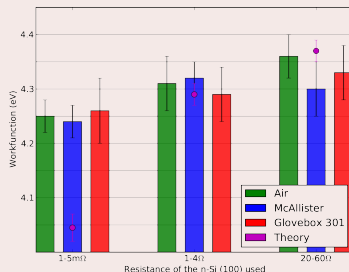
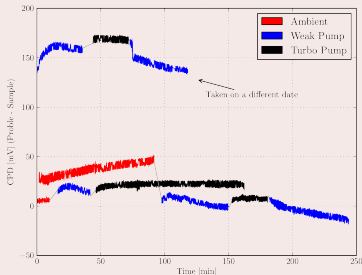
[3]



[4]

# Checking against Established Systems

## Behaviour at Room Temperature

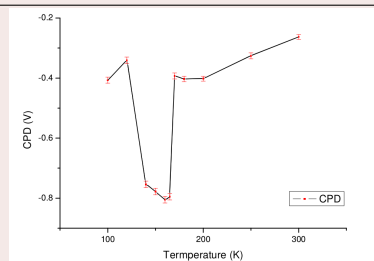
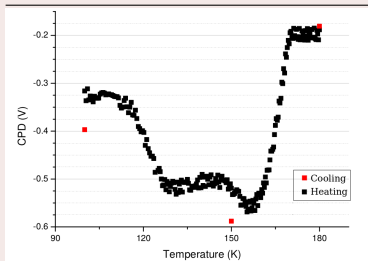


‘Jumps’ probably due to movement of probe head  
Excellent agreement between systems

# Temperature Dependent CPD in W:VO<sub>2</sub>

## Temperature Sweep and precise Measurement

Samples supplied by M. Nakano, RKIEN

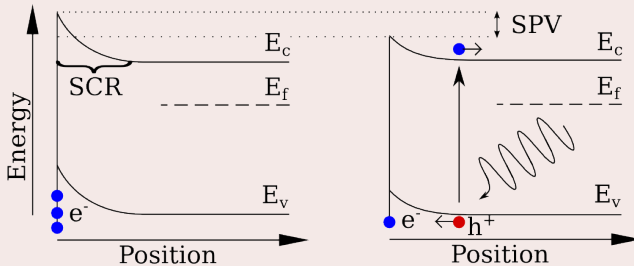


Curious behaviour in the range 120 K to 160 K, far below  $T_{MI}$   
Effect of substrate?

# Intermission: Physical Causes of SPV

## Band bending & SPV: dark vs. light

$$\text{SPV} \equiv \text{CPD}_{\text{light}} - \text{CPD}_{\text{dark}} \equiv \varphi_{s,\text{dark}} - \varphi_{s,\text{light}}$$



$$\text{SPV}_{\text{n-Type}} > 0$$

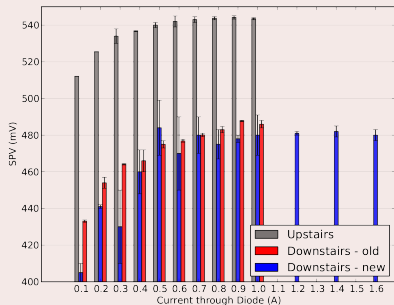
$$\text{SPV}_{\text{p-Type}} < 0$$

## Checking against Established Systems

### Behaviour at lower temperatures and SPV

20 nm Al on Si,  
oxidised by plasma

- $\phi_{\text{Alumina}}$  at 300 K:  
(4.00  $\pm$  0.12) eV
- $\phi_{\text{Alumina}}$  at 250 K:  
(4.17  $\pm$  0.15) eV

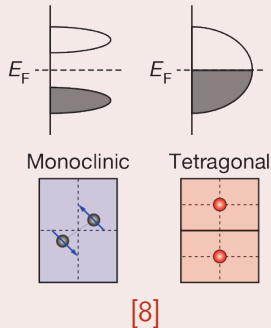


Probably no ice, even on very hydrophilic surface  
SPV  $\sim$ 12 % too low. Shadows on the sample?

# Intermission: Choosing a Model System for SPV(T)

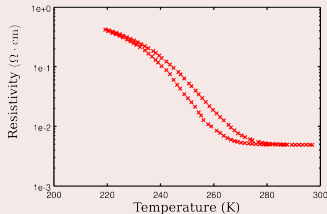
## Metal Insulator (MI) Transition in $\text{VO}_2$

- metal at  $T > T_{MI}$
- semiconductor at  $T < T_{MI}$
- insulator at  $T \ll T_{MI}$
- $T_{MI} \approx 270 \text{ K}$  [5] (W-doped)
- $\phi \approx 5.15 \text{ eV}$  [6] (at RT)
- $\Delta\phi_{MI} \approx -0.15 \text{ eV}$  [6]
- $\Delta\phi_{MI} \approx 0.45 \text{ eV}$  [7] (W-doped)

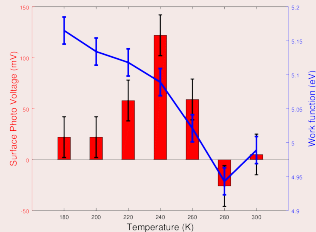


# Temperature Dependent SPV in W:VO<sub>2</sub>

## $\rho(T)$ and SPV(T)



Measurement by Nir Kedem



SPV identifies W:VO<sub>2</sub> as n-type material (agrees with W-doping)  
 $\rho(T)$  & transition at the expected temperature ([6],[9])

## Discussion & Conclusion

We showed that...

- CPD is in excellent agreement with established systems
  - SPV  $\sim 12\%$  too low. Shadowing?
  - CPD(T) reproducible and interesting
  - $\Delta\phi_{MI}$  observed before, direction & magnitude unclear
  - CPD(T) & SPV(T) reasonable
- Lakeshore + Mc Allister + LED is a viable system for SPV(T)



## List of References

### Literature and links

- [1] L. Kronik & Y. Shapira *Surf. Sci. Rep.*, 37(1-5), 1999
- [2] Besocke Website
- [3] Lakeshore Website
- [4] LEDengin Website
- [5] C. Ko *et al.* *ACS Appl. Mater. Interfaces*, 3(9), 2011
- [6] K. Shibuya *et al.* *Phys Rev. B*, 82(20), 2010
- [7] H. Yin *et al.* *ACS Appl. Mater. Interfaces*, 3(6), 2011
- [8] M. Nakano *et al.* *Nature*, 487(7408), 2012
- [9] K. Shibuya *et al.* *Appl. Phys. Lett.*, 96, 2010

## Some Background...

### ...about my M.Sc. project

- Research carried out in 13/14 at  
The Weizmann Institute of  
Science
- Project had two parts: P(VDF)  
& SPV(T)
- Only part two was presented



# Acknowledgements

## Thanks! to...

Prof. David Cahen	for his supervision
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Nir Kadem	for always having an answer